

DS1386/DS1386P **RAMified Watchdog Timekeeper**

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GENERAL DESCRIPTION

The DS1386 is a nonvolatile static RAM with a full-function real-time clock (RTC), alarm, watchdog timer, and interval timer that are all accessible in a byte-wide format. The DS1386 contains a lithium energy source and a quartz crystal, which eliminates the need for any external circuitry. Data contained within 8k or 32k by 8-bit memory and the timekeeping registers can be read or written in the same manner as byte-wide static RAM. The timekeeping registers are located in the first 14 bytes of memory space. Data is maintained in the RAMified timekeeper by intelligent control circuitry, which detects the status of V_{CC} and write protects memory when V_{CC} is out of tolerance. The lithium energy source can maintain data and real time for over ten years in the absence of V_{CC} . Timekeeper information includes hundredths of seconds, seconds, minutes, hours, day, date, month, and year. The date at the end of the month is automatically adjusted for months with less than 31 days, including correction for leap year.

The RAMified timekeeper operates in either 24hour or 12-hour format with an AM/PM indicator. The watchdog timer provides alarm interrupts and interval timing between 0.01 seconds and 99.99 seconds. The real-time alarm provides for preset times of up to one week. Interrupts for both watchdog and RTC operate when the system is powered down. Either can provide system "wakeup" signals.

FEATURES

- 8kB or 32kB of User NV RAM
- **Integrated NV SRAM, Real-Time Clock,** Crystal, Power-Fail Control Circuit, and **Lithium Energy Source**
- **Totally Nonvolatile With Over 10 Years of Operation in the Absence of Power**
- Watchdog Timer Restarts an Out-Of-**Control Processor**
- **Alarm Function Schedules Real-Time Related Activities such as System Wakeup**
- **Programmable Interrupts and Square-**Wave Output
- All Registers are Individually Addressable via the Address and Data Bus
- Interrupt Signals are Active in Power-**Down Mode**

Pin Configurations appear at end of data sheet.

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PART	TEMP RANGE	VOLTAGE (V)	PIN-PACKAGE	TOP MARK
DS1386- 8-120	0° C to $+70^{\circ}$ C	5.0	32 EMOD (0.740")	DS1386-8K-120
DS1386-8-120+	0° C to $+70^{\circ}$ C	5.0	32 EMOD (0.740")	DS1386-8K+120
DS1386-32-120	0° C to $+70^{\circ}$ C	5.0	32 EMOD (0.740")	DS1386-32K-120
DS1386-32-120+	0° C to $+70^{\circ}$ C	5.0	32 EMOD (0.740")	DS1386-32K+120
DS1386P-8-120	0° C to $+70^{\circ}$ C	5.0	34 PowerCap*	DS1386P-8K-120
DS1386P-8-120+	0° C to $+70^{\circ}$ C	5.0	34 PowerCap*	DS1386P+8K-120
DS1386P-32-120	0° C to $+70^{\circ}$ C	5.0	34 PowerCap*	DS1386P-32K-120
DS1386P-32-120+	0° C to $+70^{\circ}$ C	5.0	34 PowerCap*	DS1386P+32K-120

ORDERING INFORMATION

PIN DESCRIPTION

	P		001.	M.T.	WW 100 P COMPLET		
EM 8k x 8	OD 32k x 8	Powe 8k x 8	erCap 32k x 8	NAME	FUNCTION		
1	1	34	34	INTA	Active-Low Interrupt Output A (Open Drain)		
2	2	1	1	INTB	Active-Low Interrupt Output B (Open Drain)		
3, 28	WT.	2, 3, 31, 32	2, 3	N.C.	No Connection		
12	12	18	18	A0	TW WWW. OXCOM		
11	11	19	19	A10	A COMPANY CONTRACTION		
10	10	20	20	A2	L.T.W. W.100 1. COM.I.		
9	9	21	21	A3	M.TW WWW.100Y.COM.TW		
8	8	22	22	A4	NTW WWW. 100Y.CO.M.TW		
7	C7	23	23	A5	ONE TW WWW.LODY.COM		
6	6	24	24	A6	COM.TW WWW.1002.COM.TW		
5.10	5	25	25	A7	Address Inputs		
27	27	26	26	A8	Address Inputs		
26	26	27	27 🔨	A9	Y.COMTW WWW.100Y.COMTW		
23	23	28	28 <	A10	NY.COM TW WWWWWWWWW		
25	25	29	29	A11	WWW.LOOV.CUM		
4	4	30	30	A12	NOT COMPT		
N	28	CON I.I	31	A13	TODICONCLUM MANNA CONCL		
	3 00	- M	32	A14	(1001.COM.TW WT.1001.COM.TW		
16	16	17	17	GND	Ground		
13, 14, 15, 17– 21	13, 14, 15, 17– 21	16–9	16–9	DQ0, DQ1, DQ2, DQ3– DQ7	Data Input/Output		
22	22	8	8	CE	Active-Low Chip Enable		
24	24	7	7	ŌĒ	Active-Low Output Enable		
29	29	6 00	6	WE	Active-Low Write Enable		
30, 32	30, 32	N 1 100	Y.CO	V _{CC}	+5V Power Supply		
31	31	33	33	SQW	Square-Wave Output		
_		4	400	PFO	Active-Low Power-Fail Output		
		Win		X1, X2	Crystal Connections		
		W.	1001.	V _{BAT}	Battery Connection		

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PACKAGES

The DS1386 is available in two packages (32-pin encapsulated DIP module and 34-pin PowerCap module). The 32-pin DIP style module integrates the crystal, lithium energy source, and silicon all in one package. The 34-pin PowerCap Module Board is designed with contacts for connection to a separate PowerCap (DS9034PCX) that contains the crystal and battery. This design allows the PowerCap to be mounted on top of the DS1386P after the completion of the surface mount process. Mounting the PowerCap after the surface mount process prevents damage to the crystal and battery due to high temperatures required for solder reflow. The PowerCap is keyed to prevent reverse insertion. The PowerCap Module Board and PowerCap are ordered separately and shipped in separate containers. The part number for the PowerCap is DS9034PCX.

OPERATION—READ REGISTERS

The DS1386 executes a read cycle whenever \overline{WE} (Write Enable) is inactive (High), \overline{CE} (Chip Enable) and \overline{OE} (Output Enable) are active (Low). The unique address specified by the address inputs (A0-A14) defines which of the registers is to be accessed. Valid data will be available to the eight data output drivers within t_{ACC} (Access Time) after the last address-input signal is stable, providing that \overline{CE} and \overline{OE} access times are also satisfied. If \overline{OE} and \overline{CE} access times are not satisfied, then data access must be measured from the latter occurring signal (\overline{CE} or \overline{OE}) and the limiting parameter is either t_{CO} for \overline{CE} or t_{OE} for \overline{OE} rather than address access.

OPERATION—WRITE REGISTERS

The DS1386 is in the write mode whenever the \overline{WE} (Write Enable) and \overline{CE} (Chip Enable) signals are in the active (Low) state after the address inputs are stable. The latter occurring falling edge of \overline{CE} or \overline{WE} will determine the start of the write cycle. The write cycle is terminated by the earlier rising edge of \overline{CE} or \overline{WE} . All address inputs must be kept valid throughout the write cycle. WE must return to the high state for a minimum recovery state (t_{WR}) before another cycle can be initiated. Data must be valid on the data bus with sufficient Data Set-Up (t_{DS}) and Data Hold Time (t_{DH}) with respect to the earlier rising edge of \overline{CE} or \overline{WE} . The \overline{OE} control signal should be kept inactive (High) during write cycles to avoid bus contention. However, if the output bus has been enabled (\overline{CE} and \overline{OE} active), then \overline{WE} will disable the outputs in t_{ODW} from its falling edge.

DATA RETENTION

The RAMified Timekeeper provides full functional capability when V_{CC} is greater than 4.5V and writeprotects the register contents at 4.25V typical. Data is maintained in the absence of V_{CC} without any additional support circuitry. The DS1386 constantly monitors V_{CC} . Should the supply voltage decay, the RAMified Timekeeper will automatically write-protect itself and all inputs to the registers become "don't care." The two interrupts INTA and INTB (INTB) and the internal clock and timers continue to run regardless of the level of V_{CC} . However, it is important to insure that the pull-up resistors used with the interrupt pins are never pulled up to a value that is greater than $V_{CC} + 0.3V$. As V_{CC} falls below approximately 3.0V, a power-switching circuit turns the internal lithium energy source on to maintain the clock and timer data and functionality. It is also required to insure that during this time (battery backup mode), the voltage present at INTA and INTB (INTB) never exceeds 3.0V. During power-up, when V_{CC} rises above approximately 3.0V, the power switching circuit connects external V_{CC} and disconnects the internal lithium energy source. Normal operation can resume after V_{CC} exceeds 4.5V for a period of 200ms.

RAMIFIED TIMEKEEPER REGISTERS

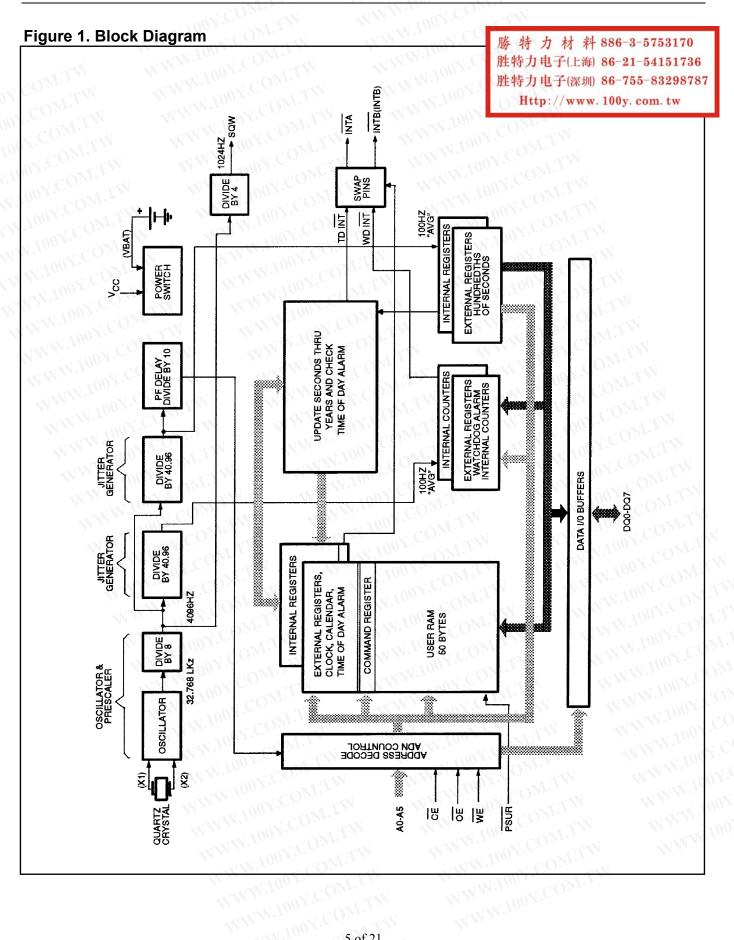
The RAMified Timekeeper has 14 registers, which are 8 bits wide that contain all of the timekeeping, alarm, and watchdog and control information. The clock, calendar, alarm, and watchdog registers are memory locations, which contain external (user-accessible) copies of the timekeeping data. The external copies are independent of internal functions except that they are updated periodically by the simultaneous transfer of the incremented internal copy (see Figure 1). The Command Register bits are affected by both internal and external functions. This register will be discussed later. The 8 or 32kbytes of RAM and the 14 external timekeeping registers are accessed from the external address and data bus. Registers 0, 1, 2, 4, 6, 8, 9, and A contain time of day and date information (see Figure 2). Time of day information is stored in BCD. Register B is the Command Register and information in this register is binary. Registers C and D are the Watchdog Alarm Registers and information, which is stored in these two registers, is in BCD. Registers E through 1FFF or 7FFF are user bytes and can be used to maintain data at the user's discretion.

CLOCK ACCURACY (DIP MODULE)

The DS1386 is guaranteed to keep time accuracy to within ± 1 minute per month at $\pm 25^{\circ}$ C.

CLOCK ACCURACY (POWERCAP MODULE)

The DS1386P and DS9034PCX are each individually tested for accuracy. Once mounted together, the module is guaranteed to keep time accuracy to within ± 1.53 minutes per month (35ppm) at $\pm 25^{\circ}$ C.



TIME-OF-DAY REGISTERS

Registers 0 through A contain time, date, and alarm data in BCD. Fifteen bits within these 11 registers are not used and will always read 0 regardless of how they are written. Bits 6 and 7 in the Months Register (9) are binary bits. When set to logic 0, $\overline{\text{EOSC}}$ (Bit 7) enables the RTC oscillator. This bit is set to logic 1 as shipped from Dallas Semiconductor to prevent lithium energy consumption during storage and shipment (DIP Module only). This bit will normally be turned on by the user during device initialization. However, the oscillator can be turned on and off as necessary by setting this bit to the appropriate level. Bit 6 of this same byte controls the square wave output. When set to logic 0, the square wave output pin will output a 1024Hz square wave signal. When set to logic 1 the square wave output pin is in a high impedance state. Bit 6 of the Hours Register is defined as the 12- or 24-hour select bit. When set to logic 1, the 12-hour format is selected. In the 12-hour format, bit 5 is the AM/PM bit with logic 1 being PM. In the 24-hour mode, bit 5 is the second 10-hour bit (20-23 hours). The Time of Day Registers are updated every 0.01 seconds from the Real Time Clock, except when the TE bit (bit 7 of Register B) is set low or the clock oscillator is not running. The preferred method of synchronizing data access to and from the RAMified Timekeeper is to access the Command Register by doing a write cycle to address location 0B and setting the TE bit (transfer enable bit) to a logic 0. This will freeze the External Time of Day Registers at the present recorded time, allowing access to occur without danger of simultaneous update. When the watch registers have been read or written, a second write cycle to location 0B, setting the TE bit to a logic 1, will put the Time of Day Registers back to being updated every 0.01 second. No time is lost in the Real Time Clock because the internal copy of the Time of Day Register buffers is continually incremented while the external memory registers are frozen. An alternate method of reading and writing the Time of Day Registers is to ignore synchronization. However, any single read may give erroneous data as the Real Time Clock may be in the process of updating the external memory registers as data is being read. The internal copies of seconds through years are incremented, and the time of day alarm is checked during the period that hundreds of seconds reads 99 and are transferred to the external register when hundredths of seconds roll from 99 to 00. A way of making sure data is valid is to do multiple reads and compare. Writing the registers can also produce erroneous results for the same reasons. A way of making sure that the write cycle has caused proper update is to do read verifies and re-execute the write cycle if data is not correct. While the possibility of erroneous results from reads and write cycles has been stated, it is worth noting that the probability of an incorrect result is kept to a minimum due to the redundant structure of the RAMified Timekeeper.

TIME-OF-DAY ALARM REGISTERS

Registers 3, 5, and 7 contain the Time of Day Alarm Registers. Bits 3, 4, 5, and 6 of Register 7 will always read 0 regardless of how they are written. Bit 7 of Registers 3, 5, and 7 are mask bits (Table 1). When all of the mask bits are logic 0, a Time of Day Alarm will only occur when Registers 2, 4, and 6 match the values stored in Registers 3, 5, and 7. An alarm will be generated every day when bit 7 of Register 7 is set to a logic 1. Similarly, an alarm is generated every hour when bit 7 of Registers 7 and 5 is set to a logic 1. When bit 7 of Registers 7, 5, and 3 is set to a logic 1, an alarm will occur every minute when Register 1 (seconds) rolls from 59 to 00.

Time of Day Alarm Registers are written and read in the same format as the Time of Day Registers. The Time of Day Alarm Flag and Interrupt are always cleared when Alarm Registers are read or written.

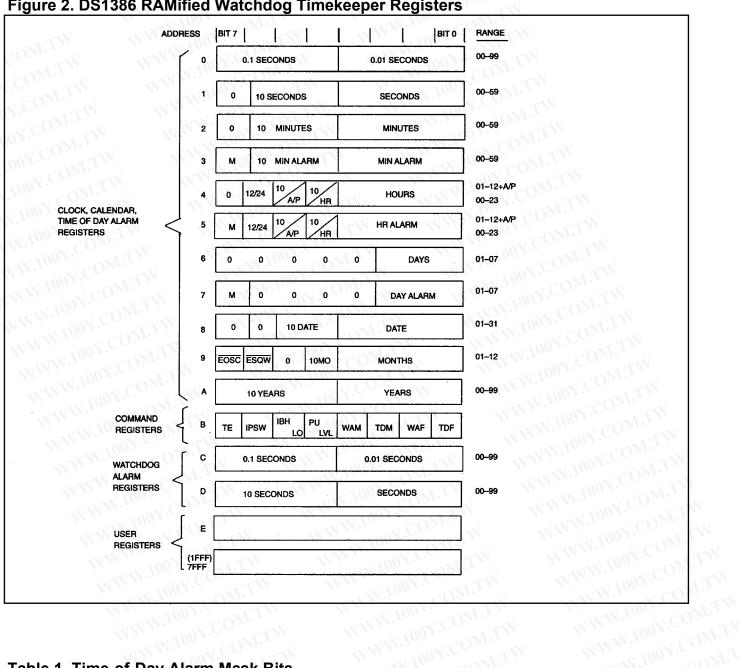
WATCHDOG ALARM REGISTERS

Registers C and D contain the time for the watchdog alarm. The two registers contain a time count from 00.01 to 99.99 seconds in BCD. The value written into the Watchdog Alarm Registers can be written or read in any order. Any access to Register C or D will cause the watchdog alarm to reinitialize and clears the watchdog flag bit and the watchdog interrupt output. When a new value is entered or the Watchdog Registers are read, the watchdog timer will start counting down from the entered value to zero. When zero is reached, the watchdog interrupt output will go to the active state. The watchdog timer countdown is interrupted and reinitialized back to the entered value every time either of the registers are accessed. In this manner, controlled periodic accesses to the watchdog timer can prevent the watchdog alarm from going to an active level. If access does not occur, countdown alarm will be repetitive. The Watchdog Alarm Registers always read the entered value. The actual countdown register is internal and is not readable. Writing registers C and D to 0 will disable the watchdog alarm feature. WWW.100Y.COM.TW

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Figure 2. DS1386 RAMified Watchdog Timekeeper Registers

Table 1. Time-of-Day Alarm Mask Bits

	WW. LON.CON	V WT	
ble 1. Time-of	-Day Alarm Mask	Bits	WWW.100X.COM.TW WWW.100
	REGISTER	Man	DESCRIPTION
(3) MINUTES	(5) HOURS	(7) DAYS	DESCIMINION
1	W. 1 1001.	11.14	Alarm Once Per Minute
0	Y001 100Y	NTN IN	Alarm When Minutes Match
0	0	LCOM IN	Alarm When Hours and Minutes Match
0	0	0 0	Alarm When Hours, Minutes and Days Match

Note: Any other bit combinations of mask bit settings produce illogical operation. WWW.100Y.COM. WWW.100

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COMMAND REGISTER

Address location 0Bh is the Command Register where mask bits, control bits and flag bits reside. The operation of each bit is as follows:

Bit 7: TE (Transfer Enable). This bit when set to a logic 0 will disable the transfer of data between internal and external clock registers. The contents in the external clock registers are now frozen and reads or writes will not be affected with updates. This bit must be set to a logic 1 to allow updates.

Bit 6: IPSW (Interrupt Switch). When set to a logic 1, \overline{INTA} is the Time of Day Alarm and INTB/(\overline{INTB}) is the Watchdog Alarm. When set to logic 0, this bit reverses the output pins. \overline{INTA} is now the watchdog alarm output and \overline{INTB}) is the time of day alarm output.

Bit 5: IBH/LO (Interrupt B Sink or Source Current). When this bit is set to a logic 1 and V_{CC} is applied, INTB/(INTB) will source current (see DC characteristics IOH). When this bit is set to a logic 0, INTB will sink current (see DC characteristics IOL).

Bit 4: PU/LVL (Interrupt Pulse Mode or Level Mode). This bit determines whether both interrupts will output a pulse or level signal. When set to a logic 0, \overline{INTA} and $\overline{INTB}/(\overline{INTB})$ will be in the level mode. When this bit is set to a logic 1, the pulse mode is selected and \overline{INTA} will sink current for a minimum of 3ms and then release. $\overline{INTB}/(\overline{INTB})$ will either sink or source current, depending on the condition of Bit 5, for a minimum of 3ms and then release. \overline{INTB} will only source current when there is a voltage present on V_{CC}.

Bit 3: WAM (Watchdog Alarm Mask). When this bit is set to a logic 0, the watchdog interrupt output will be activated. The activated state is determined by bits 1,4,5, and 6 of the Command Register. When this bit is set to a logic 1, the watchdog interrupt output is deactivated.

Bit 2: TDM (Time-of-Day Alarm Mask). When this bit is set to a logic 0, the time of day alarm interrupt output will be activated. The activated state is determined by bits 0,4,5, and 6 of the Command Register. When this bit is set to a logic 1, the time of day alarm interrupt output is deactivated.

Bit 1: WAF (Watchdog Alarm Flag). This bit is set to a logic 1 when a watchdog alarm interrupt occurs. This bit is read only. The bit is reset when any of the watchdog alarm registers are accessed. When the interrupt is in the pulse mode (see bit 4 definition), this flag will be in the logic 1 state only during the time the interrupt is active.

Bit 0: TDF (Time-of-Day Flag). This is a read-only bit. This bit is set to a logic 1 when a time of day alarm has occurred. The time the alarm occurred can be determined by reading the time of day alarm registers. This bit is reset to a logic 0 state when any of the time of day alarm registers are accessed.

When the interrupt is in the pulse mode (see bit 4 definition), this flag will be in the logic 1 state only during the time the interrupt is active.

ABSOLUTE MAXIMUM RATINGS	勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 — 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw	DS1386/1386P
Voltage Range on Any Pin Relative to Ground	WW 1002. M.EW	0.3V to +7.0V
Operating Temperature Range	Who we want	$\dots 0^{\circ}$ C to $+70^{\circ}$ C
Storage Temperature Range		40°C to +70°C
Soldering Temperature	See IPC/JEDEC J-STD-020 Specifica	tion (See Note 14)

This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS

$(I_A = 0^{\circ}C \text{ to } + 70^{\circ}C)$	N. IV. CO	NI.	NW. CO		
PARAMETER	SYMBOL	MIN	TYP MAX	UNITS	NOTES
Supply Voltage	V _{CC}	4.5	5.0 5.5	V	10
Input Logic 1	V _{IH}	2.2	$V_{CC} + 0.3$	V	10
Input Logic 0	V _{IL}	-0.3	+0.8	V	10

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS	NOTES
Input Leakage Current	IIL	-1.0	OM.TW	+1.0	μΑ	OM.TW
Output Leakage Current	I _{LO}	-1.0	COM.TW	+1.0	μA	COWLIN
I/O Leakage Current	I _{LIO}	-1.0	LCOM. TV	+1.0	μA	LCOM.
Output Current at 2.4V	I _{OH}	-1.0	Y.COM.T	N N	mA	N.COM
Output Current at 0.4V	IOL	WWW.	OV.COM	2.1	mA	13
Standby Current $\overline{CE} = 2.2V$	I _{CCS1}	WWW.	3.0	7.0	mA	1001 1001
Standby Current $\overline{CE} = V_{CC} - 0.5$	I _{CCS2}	WWW	2.0	4.0	mA	N.100Y.C
Active Current	CO I _{CC}	WW	W.100 Y.C	85	mA	W.100Y
Write Protection Voltage	V _{TP}	4.0	4.25	4.5	V 🚿	100

CAPACITANCE

 $(T_{A} = 25^{\circ}C)$ NOTES PARAMETER **SYMBOL** MIN TYP MAX UNITS Input Capacitance 7 15 CIN pF **Output Capacitance** 7 15 pF COUT 7 15 Input/Output Capacitance pF $C_{I/O}$

AC ELECTRICAL CHARACTERISTICS

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	WIIM		XX-120		
PARAMETER	SYMBOL	MIN	MAX	UNITS	NOTE
Read Cycle Time	t _{RC}	120	TODY.COM	ns	1
Address Access Time	t _{ACC}		120	ns	
CE Access Time	c ^o t _{co}	WW	120	ns	
OE Access Time	t _{OE}	WW	100	ns	
\overline{OE} or \overline{CE} to Output Active	t _{COE}	10	NW. POOY.C	ns	
Output High-Z from Deselect	t _{OD}	W W	40	ns	
Output Hold from Address Change	t _{OH}	10	WWW.1005	ns	
Write Cycle Time	t _{wc}	120	WWW.100	ns	N
Write Pulse Width	t _{WP}	110	WWW.	ns	3
Address Setup Time	t _{AW}	0	WWW	ns	TW
Write Recovery Time	t _{WR}	10	MMM.	ns	WT.
Output High-Z from WE	t _{oDW}	WIN	40	ns	WT.IN
Output Active from WE	t _{OEW}	10	MW	ns	WT.M
Data Setup Time	t _{DS}	85	NN	ns	4
Data Hold Time	t _{DH}	10	N W	ns	4, 5
INTA, INTB Pulse Width	t _{IPW}	3	N N	ms	11, 12

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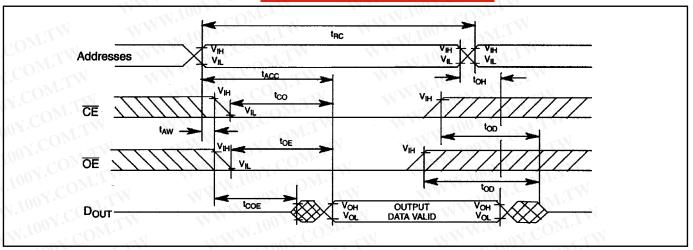
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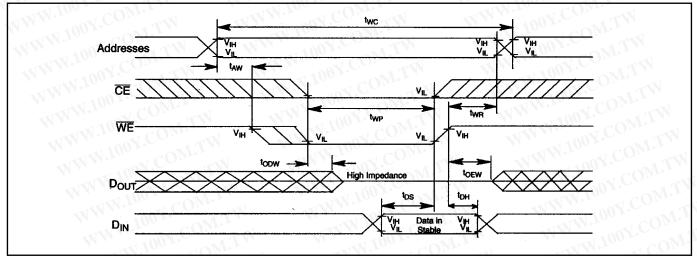


READ CYCLE (Note 1)

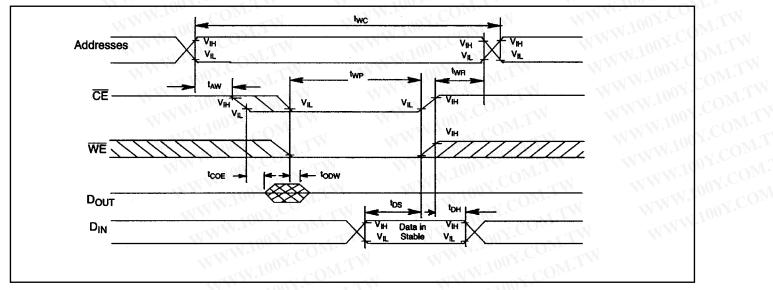
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WRITE CYCLE 1 (Notes 2, 6, 7)

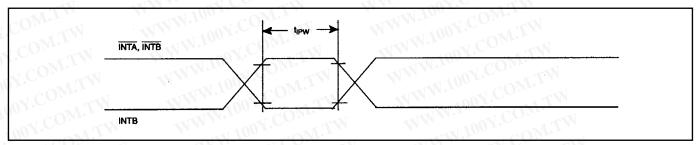


WRITE CYCLE 2 (Notes 2, 8)



TIMING DIAGRAM—INTERRUPT OUTPUTS PULSE MODE

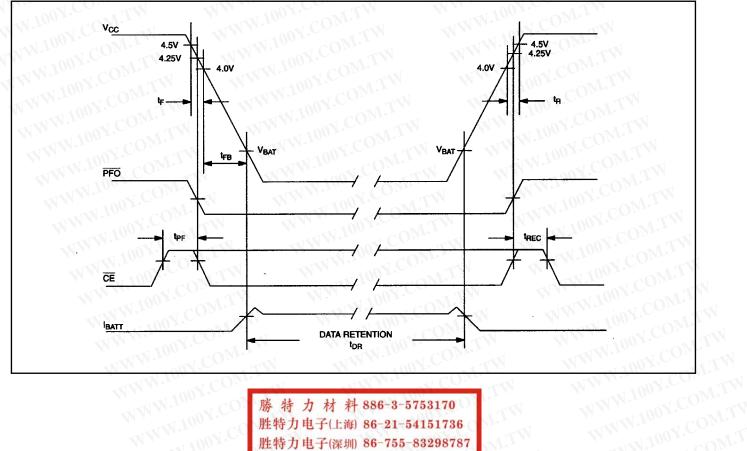
(See Notes 11 and 12)



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POWER-DOWN/POWER-UP TIMING



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PARAMETER	SYMBOL	MIN	MAX	UNITS	NOTES
CE High to Power Fail	t _{PF}	WW.100	0	ns	
Recovery at Power-Up	t _{REC}	WWW.10	200	ms	
V _{CC} Slew Rate Power-Down	$t_{F} \\ 4.0 \leq V_{CC} \leq 4.5 V$	300	100Y.CON	μs	
V _{CC} Slew Rate Power-Down	$t_{FB} \\ 3.0 \leq V_{CC} \leq 4.25 V \label{eq:tFB}$	10		μs	
V _{CC} Slew Rate Power-Up	$\begin{array}{c} t_{R} \\ 4.5V \geq V_{CC} \geq \\ 4.0V \end{array}$	0	WW.100X.	μs	
Expected Data Retention	t _{DR} COM	10	WWW.100	Years	N 9

WARNING: Under no circumstances are negative undershoots, of any amplitude, allowed WWW.100Y.COM WWW.100Y.COM.T WWW.100 when device is in battery-backup mode.

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NOTES:

- 1) $\overline{\text{WE}}$ is high for a read cycle.
- 2) $\overline{OE} = V_{IH}$ or V_{IL} . If $\overline{OE} = V_{IH}$ during write cycle, the output buffers remain in a high impedance state.
- 3) t_{WP} is specified as the logical AND of the \overline{CE} and \overline{WE} . t_{WP} is measured from the latter of \overline{CE} or \overline{WE} going low to the earlier of \overline{CE} or \overline{WE} going high.
- 4) t_{DS} or t_{DH} are measured from the earlier of \overline{CE} or \overline{WE} going high.
- 5) t_{DH} is measured from WE going high. If \overline{CE} is used to terminate the write cycle, then $t_{DH} = 20$ ns for -120 parts and $t_{DH} = 25$ ns for -150 parts.
- 6) If the \overline{CE} low transition occurs simultaneously with or later than the \overline{WE} low transition in write cycle 1, the output buffers remain in a high impedance state during this period.
- 7) If the \overline{CE} high transition occurs prior to or simultaneously with the \overline{WE} high transition, the output buffers remain in a high impedance state during this period.
- 8) If \overline{WE} is low or the \overline{WE} low transition occurs prior to or simultaneously with the \overline{CE} low transition, the output buffers remain in a high impedance state during this period.
- 9) Each DS1386 is marked with a four-digit date code AABB. AA designates the year of manufacture. BB designates the week of manufacture. The expected t_{DR} is defined for DIP modules as starting at the date of manufacture.
- 10) All voltages are referenced to ground.
- 11) Applies to both interrupt pins when the alarms are set to pulse.
- 12) Interrupt output occurs within 100ns on the alarm condition existing.
- 13) Both INTA and INTB (INTB) are open-drain outputs.
- 14) Real-Time Clock modules (DIP) can be successfully processed through conventional wave-soldering techniques as long as temperature exposure to the lithium energy source contained within does not exceed +85°C. Post solder cleaning with water washing techniques is acceptable, provided that ultrasonic vibration is not used.

In addition, for the PowerCap version:

- a. Dallas Semiconductor recommends that PowerCap module bases experience one pass through solder reflow oriented with the label side up ("live-bug").
- b. Hand soldering and touch-up: Do not touch or apply the soldering iron to leads for more than 3 seconds. To solder, apply flux to the pad, heat the lead frame pad and apply solder. To remove the part, apply flux, heat the lead frame pad until the solder reflows and use a solder wick to remove solder.

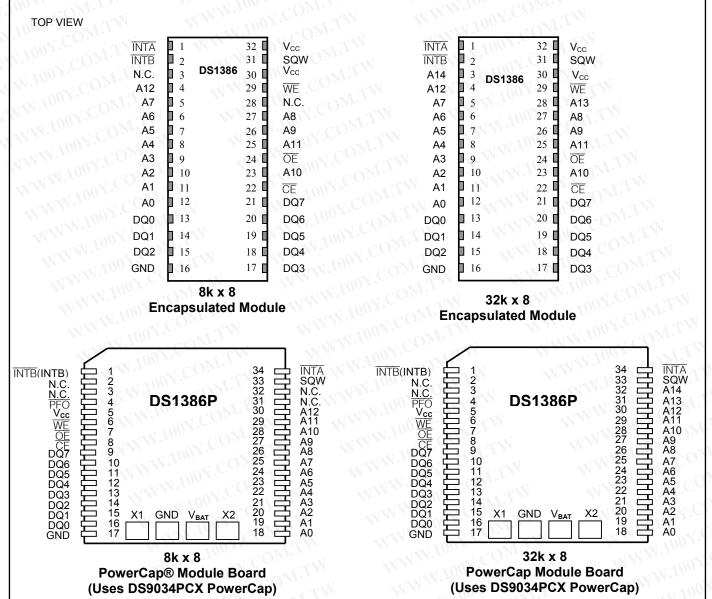
AC TEST CONDITIONS

Input Levels: 0V to 3V Transition Times: 5ns

AC TEST CONDITIONS

Output Load: 50pF + 1TTL Gate Input Pulse Levels: 0 to 3.0V Timing Measurement Reference Levels Input: 1.5V Output: 1.5V Input Pulse Rise and Fall Times: 5ns

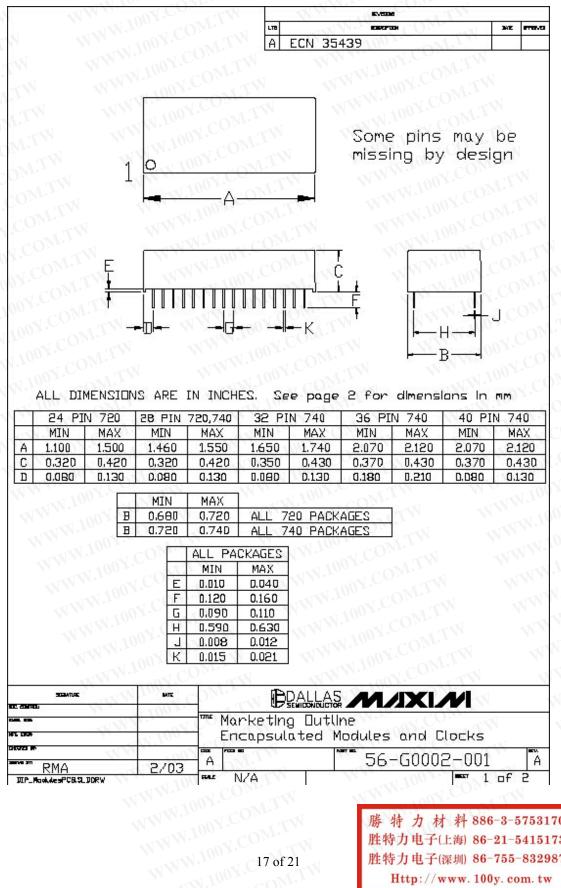
PIN CONFIGURATIONS



PACKAGE INFORMATION

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/DallasPackInfo.)

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胜特力电子(上海)	86-21-54151736
胜特力电子(深圳)	86-755-83298787
Http://www.	100y. com. tw

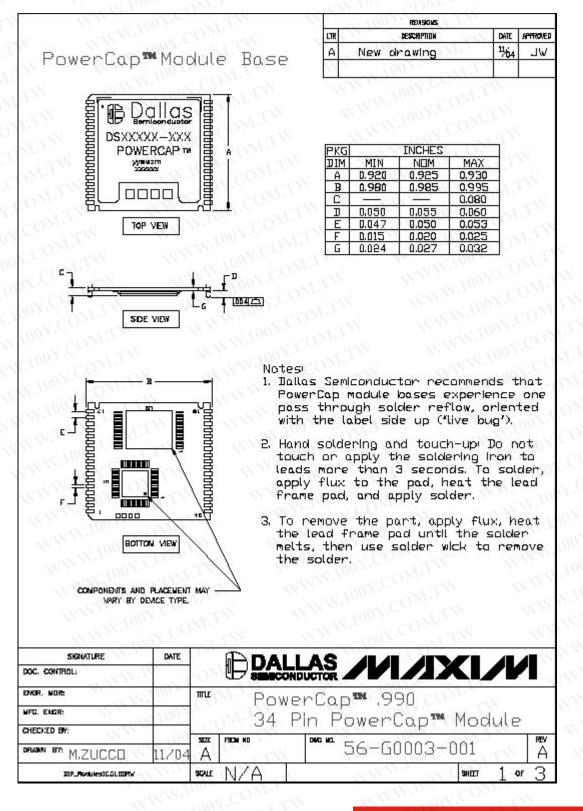
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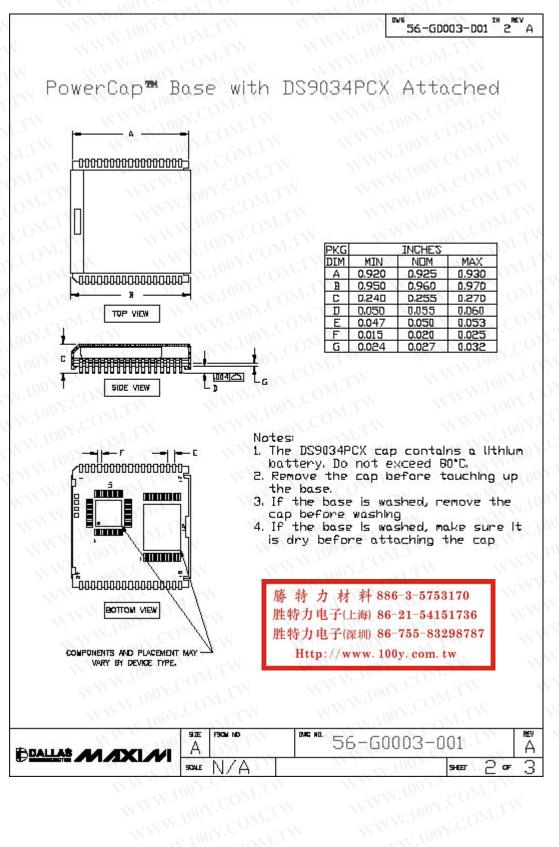
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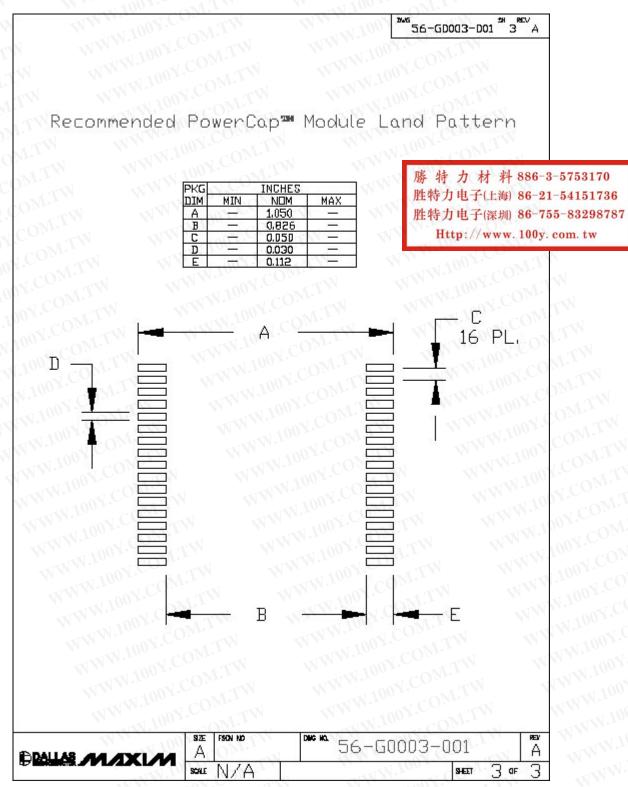
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